

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## MPQ6002 MPQ6502

## SILICON QUAD **COMPLEMENTARY TRANSISTORS**



www.centralsemi.com

# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR MPQ6002 and MPQ6502 types are silicon complementary pair transistors, mounted in a 14 pin DIP package, designed for general purpose amplifier and switching applications.

## MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Base Voltage	$V_{EBO}$	5.0	V
Continuous Collector Current	I <sub>C</sub>	500	mA
Power Dissipation (per transistor)	$P_{D}$	650	mW
Power Dissipation (total package)	$P_{D}$	1.25	W
Operating and Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
Thermal Resistance (total package)	ΘΙΑ	100	°C/W

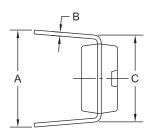
Thermal Res		Θ <sub>JA</sub>	100		°C/W
ELECTRICA SYMBOL ICBO	L CHARACTERISTICS PER TRANSISTOI TEST CONDITIONS V <sub>CB</sub> =50V	R: (T <sub>A</sub> =25°C) MIN	TYP	<b>MAX</b> 30	<b>UNITS</b> nA
I <sub>EBO</sub>	V <sub>EB</sub> =3.0V			30	nA
BV <sub>CBO</sub>	I <sub>C</sub> =10μA	60			V
<b>BVCEO</b>	I <sub>C</sub> =10mA	30			V
BVEBO	I <sub>E</sub> =10μA	5.0			V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			0.4	V
VCE(SAT)	I <sub>C</sub> =300mA, I <sub>B</sub> =30mA			1.4	V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			1.3	V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =300mA, I <sub>B</sub> =30mA			2.0	V
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =1.0mA	50			
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	75			
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	100			
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =300mA	30			
f <sub>T</sub>	$V_{CE}$ =20V, $I_{C}$ =50mA, f=100MHz	200			MHz
$C_{ob}$	$V_{CB}$ =10V, $I_E$ =0, f=1.0MHz			8.0	pF
C <sub>ib</sub>	$V_{EB}$ =2.0V, $I_{C}$ =0, f=1.0MHz			30	pF
ton	$V_{CC}$ =30V, $V_{BE}$ =0.5V, $I_{C}$ =150mA, $I_{B1}$ =15	5mA	30		ns
toff	$V_{CC}$ =30V, $I_{C}$ =150mA, $I_{B1}$ = $I_{B2}$ =15mA		225		ns

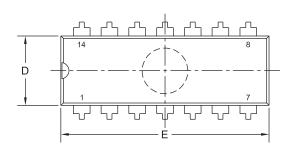
## MPQ6002 MPQ6502

# SILICON QUAD COMPLEMENTARY TRANSISTORS



## **TO-116 CASE - MECHANICAL OUTLINE**





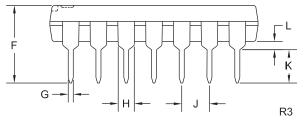
DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.310	0.390	7.9	9.9			
В	0.008	0.014	0.2	0.4			
С	0.310		7.9				
D	0.240	0.260	6.1	6.6			
Е	0.740	0.760	18.8	19.3			
F	-	0.300	-	7.6			
G	0.014	0.022	0.4	0.6			
Н	0.050		1.3				
J	0.100		2.5				
K	0.125	0.150	3.2	3.8			
L	0.015	-	0.4	-			

TO-116 (REV: R3)

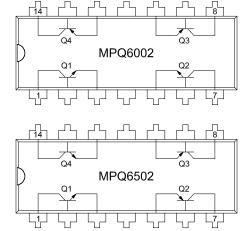
# LEAD CODE:

1) Collector Q1 8) Collector Q3
2) Base Q1 9) Base Q3
3) Emitter Q1 10) Emitter Q3
4) No Connection 11) No Connection 5) Emitter Q2 12) Emitter Q4
6) Base Q2 13) Base Q4
7) Collector Q2 14) Collector Q4

# MARKING: FULL PART NUMBER



# **PIN CONFIGURATIONS**



R1 (8-April 2013)

#### **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- · Special wafer diffusions
- PbSn plating options
- · Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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